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# **BCW89**

# **PNP General Purpose Amplifier**

- This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 300mA.
- Sourced from process 68.



1. Base 2. Emitter 3. Collector

# Absolute Maximum Ratings \* T<sub>C</sub>=25°C unless otherwise noted

| Symbol                            | Parameter                        |              | Value      | Units |
|-----------------------------------|----------------------------------|--------------|------------|-------|
| V <sub>CEO</sub>                  | Collector-Emitter Voltage        |              | -60        | V     |
| V <sub>CES</sub>                  | Collector-Emitter Voltage        |              | -60        | V     |
| V <sub>EBO</sub>                  | Emitter-Base Voltage             |              | -5.0       | V     |
| I <sub>C</sub>                    | Collector current                | - Continuous | -500       | mA    |
| T <sub>J</sub> , T <sub>stg</sub> | Junction and Storage Temperature |              | -55 ~ +150 | °C    |

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- NOTES:

  1) These ratings are based on a maximum junction temperature of 150 degrees C.

  2) These are state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                       | Parameter                            | Test Condition                                | Min. | Max.  | Units |
|------------------------------|--------------------------------------|---|------|-------|-------|
| Off Charac                   | Off Characteristics                  |   |      |       |       |
| V <sub>(BR)CBO</sub>         | Collector-Base Breakdown Voltage     | $I_C = -10\mu A, I_E = 0$                     | -80  |       | V     |
| V <sub>(BR)CEO</sub>         | Collector-Emitter Breakdown Voltage  | $I_C = -2.0 \text{mA}, I_B = 0$               | -60  |       | V     |
| V <sub>(BR)CES</sub>         | Collector-Emitter Breakdown Voltage  | $I_C = -10\mu A, I_E = 0$                     | -60  |       | V     |
| V <sub>(BR)EBO</sub>         | Emitter-Base Breakdown Voltage       | $I_C = -10\mu A, I_C = 0$                     | -5.0 |       | V     |
| I <sub>CBO</sub>             | Collector Cutoff Current             | $V_{CB} = -20V, I_{E} = 0$                    |      | -100  | nA    |
|                              |                                      | $V_{CB} = -20V, I_E = 0, T_A = +100^{\circ}C$ |      | -10   | μΑ    |
| On Charact                   | teristics                            |   |      |       |       |
| h <sub>FE</sub>              | DC Current Gain                      | $V_{CE} = -5.0V, I_{C} = -2.0mA$              | 120  | 260   |       |
| V <sub>CE(sat)</sub>         | Collector-Emitter Saturation Voltage | $I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$   |      | -0.3  | V     |
| V <sub>BE(on)</sub>          | Base-Emitter On Voltage              | $V_{CE} = -5.0V, I_{C} = -2.0mA$              | -0.6 | -0.75 | V     |
| Small Signal Characteristics |                                      |   |      |       |       |
| NF                           | Noise Figure                         | $V_{CE} = -5.0V, I_{C} = -200\mu A$           |      | 10    | dB    |
|                              |                                      | $R_S = 2.0k\Omega$ , $f = 1.0kHz$             |      |       |       |
|                              |                                      | $B_W = 200Hz$                                 |      |       |       |

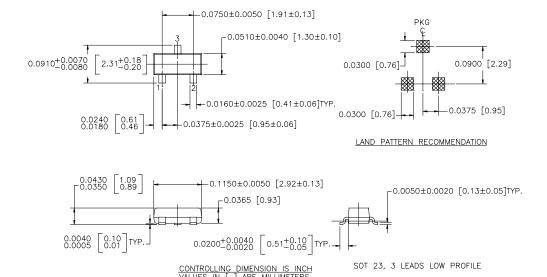
# Thermal Characteristics $T_A=25$ °C unless otherwise noted

| Symbol          | Parameter                               | Max. | Units |
|-----------------|---|------|-------|
| P <sub>D</sub>  | Total Device Dissipation                | 350  | mW    |
|                 | Derate above 25°C                       | 2.8  | mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 357  | °C/W  |

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# **Package Dimensions**

# **SOT-23**



NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

Dimensions in Millimeters

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|----------------------------|---------------------|------------------------|--------------------------|------------------------|
| ActiveArray™               | FACT Quiet series™  | ISOPLANAR™             | POP™                     | Stealth™               |
| Bottomless™                | FAST <sup>®</sup>   | LittleFET™             | Power247™                | SuperSOT™-3            |
| CoolFET™                   | FASTr™              | MicroFET™              | PowerTrench <sup>®</sup> | SuperSOT™-6            |
| CROSSVOLT™                 | FRFET™              | MicroPak™              | QFET™                    | SuperSOT™-8            |
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|--------------------------|---------------------------|---|
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